EMPOWER RF SYSTEMS, INC.

Solid State Broadband High Power Amplifier

1066 - BBM1C3CHM | 1 – 100 MHz / 50 Watts

The BBM1C3CHM (SKU 1066) is suitable for high power broadband RF, VHF and band specific linear applications. This amplifier utilizes Silicon push-pull MOSFET power devices that provide high gain, wide dynamic range, low distortions, and good linearity. Exceptional performance, long term reliability and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, EMI/RFI filters, machined housings and qualified components. Empower RF's ISO9001 Quality Assurance Program assures consistent performance and the highest reliability.

- Solid-state Class AB design
- Instantaneous ultra broadband
- Small and lightweight
- Built-in functions and protection circuits
- Suitable for CW, AM, and FM (Consult factory for other modulation types)
- 50 ohm input/output impedance
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS @ +28V_{DC}, 25°C, 50Ω System

Parameter	Symbol	Min	Typ	Max	Unit
Operating Frequency	BW	1		100	MHz
Output Power CW	P_{SAT}	50			Watt
Output Power @ 1dB Gain Compression	P_{1dB}	30			Watt
Power Gain @ 1dB Gain Compression	G_{1dB}	46			dB
Input Power for Rated P_{SAT}	P_{IN}		0	3	dBm
Small Signal Gain Flatness	ΔG		±1.0	±1.5	dB
Input Return Loss	S_{11}			-10	dB
Noise Figure @ Max. Gain	NF		7	10	dB
Third Order Intercept Point 2-Tone @ 33dBm/Tone, 100kHz Spacing	IP3		+54		dBm
Harmonics @ P_{OUT} = 30W	H		-20		dBc
Spurious Signals	Spur		-70	-60	dBc
Operating Voltage	V_{DC}	24	28	32	Volt
Current Consumption @ P_{OUT} = 50W CW	I_{DD}			7	Amp

MECHANICAL SPECIFICATIONS

Parameter	Value	Unit
Dimension	6.4 x 3.4 x 1.0	Inch
Weight	1.0	Pound
RF Connectors Input / Output	Type-SMA, Female	
DC Interface Connector	D-Sub 9-Pin, Male	
Cooling	External Heatsink (Not Supplied)	

ENVIRONMENTAL CHARACTERISTICS (Design to Meet)

Parameter	Symbol	Min	Typ	Max	Unit
Operating Case Temperature	T_C	0		+50	°C
Non-operating Temperature	T_{STG}	-40		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F Method 500.4)	ALT			30,000	Feet
Vibration/Shock MIL-STD-810F – Method 514.5/516.5 – Proc I	VI/SH		Airborne		

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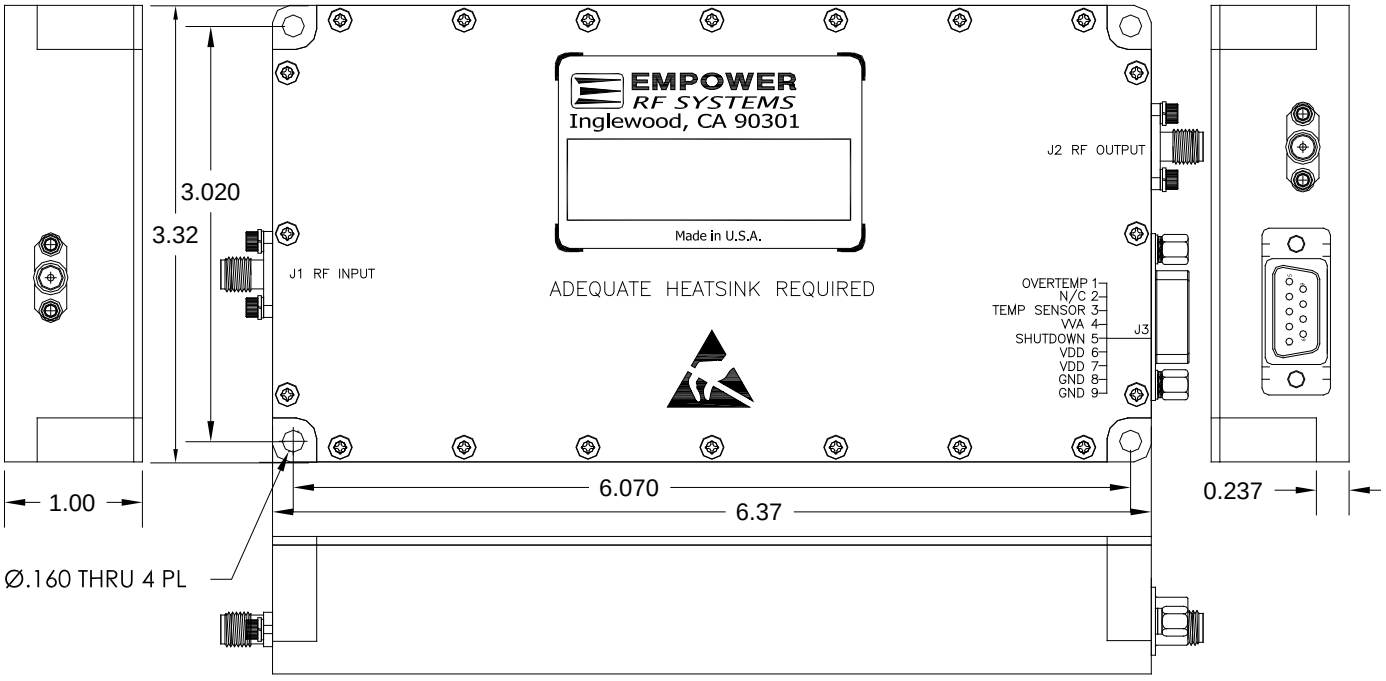
LIMITS

Input RF drive level without damage	+10 dBm	Max
Load VSWR @ P_{OUT} = 30W	∞ @ all load phase and amplitude for duration of 1 minute 3:1 @ all load phase & amplitude continuous	-
Thermal Overload	85°C shutdown	Max

DC INTERFACE CONNECTOR – D-Sub 9-Pin, Male

Pin #	Description	Specification
1	Over Temp	Over Temp Alarm: TTL Logic Low (0V) (*Normally Open*)
2	N/C	No Connection
3	Temp Sensor	Analog voltage relative to Module's Temperature @ 10mV/°C
4	VVA	Control voltage range, 0-5V_{DC} Maximum Gain = 0V_{DC}, Minimum Gain = 5V_{DC}
5	Shutdown	Amplifier Disable: TTL Logic High (5V) (*Internally Pulled-Low*)
6&7	VDD	+26.0-30.0V_{DC}
8&9	GND	Ground

OUTLINE DRAWING



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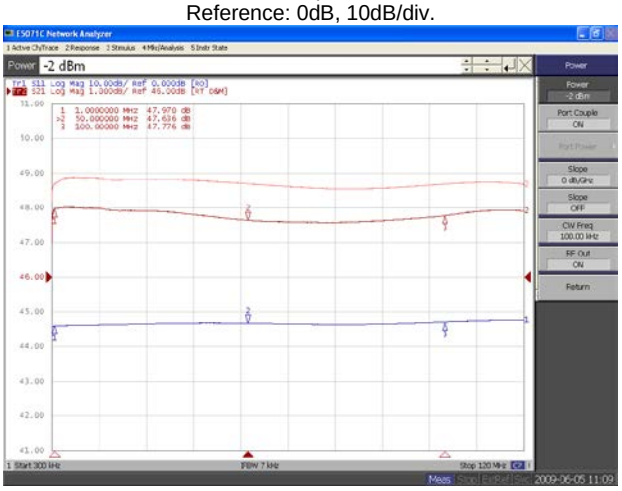
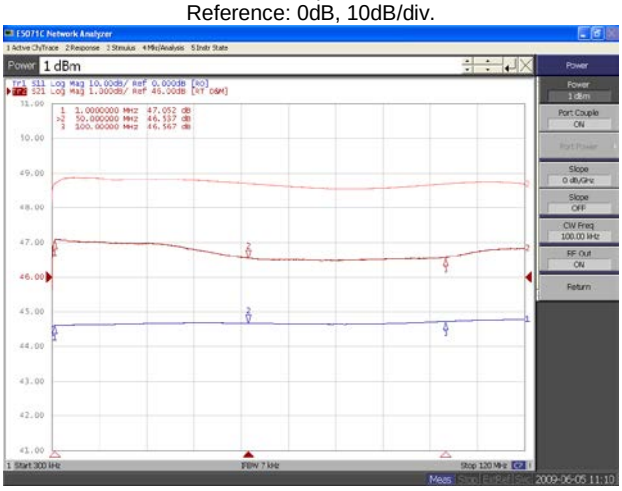
TYPICAL PERFORMANCE PLOTS

Plot 1 – Small Signal Gain and P_{1dB}
Top Curve: Small Signal Gain @ P_{IN} = -20dBm
Middle Curve: Power Gain @ P_{1dB}, P_{IN} = -2.0dBm
Reference: 46dB, 1dB/div.
Bottom Curve: Input Return Loss
Reference: 0dB, 10dB/div.



Plot 2 – Small Signal Gain and P_{SAT}
Top Curve: Small Signal Gain @ P_{IN} = -20dBm
Middle Curve: Power Gain @ P_{SAT}, P_{IN} = +1.0dBm
Reference: 46dB, 1dB/div.
Bottom Curve: Input Return Loss
Reference: 0dB, 10dB/div.



Plot 3 – Gain Adjustment Range, P_{IN} = -20dBm
Top Curve: Maximum Gain, VVA_{CTRL} = 0V
Middle Curve: Minimum Gain, VVA_{CTRL} = 5V
Reference: 20dB, 10dB/div.
Bottom Curve: Input Return Loss @ Minimum Gain
Reference: 0dB, 10dB/div.